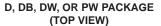
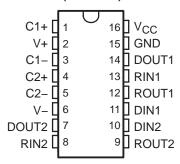


- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates Up To 250 kbit/s
- Two Drivers and Two Receivers
- Low Supply Current . . . 300 μA Typical
- External Capacitors . . . $4 \times 0.1 \mu F$
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s) MAX3232
- Applications
 - Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment





SOP-16

ORDERING INFORMATION

| TA | PACKA | PACKAGE [†] | |
|---------------|------------|----------------------|-------------|
| | 0010 (000) | Tube of 40 | |
| | SOIC (CDR) | Reel of 2500 | MAX3232 |
| | COIC (DW) | Tube of 40 | WINNOZOZ |
| _0°C to 70°C | SOIC (DW) | Reel of 2000 | |
| -0°C to 70°C | CCOD (DD) | Tube of 80 | |
| | SSOP (DB) | Reel of 2000 | MAX3232DB |
| | TSSOP (PW) | Tube of 90 | WW CKOZOZOD |
| | | Reel of 2000 | |
| | 0010 (277) | Tube of 40 | |
| | SOIC (CDR) | Reel of 2500 | MAX3232I |
| | COIC (DW) | Tube of 40 | IVIAASZSZI |
| 400C to 950C | SOIC (DW) | Reel of 2000 | |
| -40°C to 85°C | CCOD (DD) | Tube of 80 | |
| | SSOP (DB) | Reel of 2000 | MAX3232IP |
| | TSSOR (DW) | Tube of 90 | WANGEGEN |
| | TSSOP (PW) | Reel of 2000 | |



The MAX3232 device consists of two line drivers, two line receivers, and a dual charge-pump circuit with ± 15 -kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/ μ s driver output slew rate.

Function Tables

EACH DRIVER

| INPUT DIN | OUTPUT DOUT |
|--------------|----------------|
| L | Н |
| Н | L |

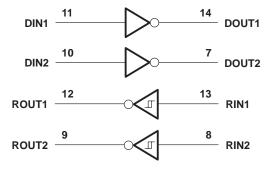
H = high level, L = low level

EACH RECEIVER

| INPUT RIN | OUTPUT ROUT |
|--------------|----------------|
| L | Н |
| Н | L |
| Open | Н |

$$\begin{split} H &= \text{high level, } L = \text{low} \\ \text{level, } Open &= \text{input} \\ \text{disconnected} & \text{or} \\ \text{connected driver off} \end{split}$$

logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage range, V _{CC} (see Note 1) | 0.3 V to 6 V |
|---|----------------------------------|
| Positive output supply voltage range, V+ (see Note 1) | –0.3 V to 7 V |
| Negative output supply voltage range, V- (see Note 1) | 0.3 V to –7 V |
| Supply voltage difference, V+ - V- (see Note 1) | 13 V |
| Input voltage range, V _I : Drivers | 0.3 V to 6 V |
| Receivers | |
| Output voltage range, VO: Drivers | |
| Receivers | 0.3 V to V _{CC} + 0.3 V |
| Package thermal impedance, θ_{JA} (see Notes 2 and 3): | CDR package73 °C/W |
| | DB package 82°C/W |
| | DW package 57°C/W |
| | PW package 108°C/W |
| Operating virtual junction temperature, T _J | 150°C |
| Storage temperature range, T _{stg} | –65°C to 150°C |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to network GND.
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 4)

| | | | | MIN | NOM | MAX | UNIT |
|---------------------------|---------------------------------|-----|-------------------------|-----|-----|-----|------|
| | Supply voltage | | V _{CC} = 3.3 V | 3 | 3.3 | 3.6 | ., |
| | | | $V_{CC} = 5 V$ | 4.5 | 5 | 5.5 | V |
| ., | Debuga high laveling streets as | DIN | V _{CC} = 3.3 V | 2 | | | ., |
| VIH | Driver high-level input voltage | DIN | V _{CC} = 5 V | 2.4 | | | V |
| V _{IL} | Driver low-level input voltage | | DIN | | | 0.8 | V |
| V | Driver input voltage | | DIN | 0 | | 5.5 | |
| VI Receiver input voltage | | | -25 | | 25 | V | |
| Τ. | | | MAY222 | 0 | | 70 | 20 |
| TA | Operating free-air temperature | | MAX3232 | -40 | | 85 | °C |

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V $_{CC}$ = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V $_{CC}$ = 5 V \pm 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP‡ | MAX | UNIT |
|----|----------------|-----------------|--------------------------------|-----|------|-----|------|
| IC | Supply current | No load, | V _{CC} = 3.3 V or 5 V | | 0.3 | 1 | mA |

[‡] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP† | MAX | UNIT |
|----------------|------------------------------|--|-----------------------|-----|-------|-----|------|
| Vон | High-level output voltage | DOUT at $R_L = 3 \text{ k}\Omega$ to GND, | DIN = GND | 5 | 5.4 | | V |
| VOL | Low-level output voltage | DOUT at R _L = $3 \text{ k}\Omega$ to GND, | DIN = VCC | -5 | -5.4 | | V |
| lн | High-level input current | VI = VCC | | | ±0.01 | ±1 | μΑ |
| IIL | Low-level input current | V _I at GND | | | ±0.01 | ±1 | μΑ |
| la at | Chart singuit autout auront | V _{CC} = 3.6 V, | VO = 0 V | | 125 | -00 | A |
| los‡ | Short-circuit output current | V _{CC} = 5.5 V, | VO = 0 V | | ±35 | ±60 | mA |
| r _O | Output resistance | V_{CC} , V+, and V- = 0 V, | V _O = ±2 V | 300 | 10M | | Ω |

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP† | MAX | UNIT |
|--------------------|------------------------------|--|---------------------------------------|-----|------|-----|--------|
| | Maximum data rate | C _L = 1000 pF, One DOUT switching, | $R_L = 3 kΩ$, See Figure 1 | 150 | 250 | | kbit/s |
| t _{sk(p)} | Pulse skew§ | C _L = 150 pF to 2500 pF | R_L = 3 kΩ to 7 kΩ, See Figure 2 | | 300 | | ns |
| CD/tr\ | Slew rate, transition region | $R_L = 3 k\Omega$ to $7 k\Omega$, | C _L = 150 pF to 1000 pF | 6 | | 30 | \//uo |
| SR(tr) | (see Figure 1) | V _{CC} = 3.3 V | C _L = 150 pF to 2500 pF | 4 | | 30 | V/μs |

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

^{\$} Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V $_{CC}$ = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V $_{CC}$ = 5 V \pm 0.5 V.

[§] Pulse skew is defined as |tpLH - tpHL| of each channel of the same device.



RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

| | PARAMETER | TEST CONDITIONS | MIN | TYP [†] | MAX | UNIT |
|------------------|---|--|----------|------------------------|-----|------|
| Vон | High-level output voltage | I _{OH} = -1 mA | VCC-0.6V | V _{CC} -0.1 V | | V |
| VOL | Low-level output voltage | I _{OL} = 1.6 mA | | | 0.4 | V |
| \/ | Decisive main a insent three held veltage | V _{CC} = 3.3 V | | 1.5 | 2.4 | ., |
| V _{IT+} | Positive-going input threshold voltage | V _{CC} = 5 V | | 1.8 | 2.4 | V |
| ., | N. d. i i i i i i i i i i i i i i i i i i | V _{CC} = 3.3 V | 0.6 | 1.2 | | ., |
| VIT- | Negative-going input threshold voltage | V _{CC} = 5 V | 0.8 | 1.5 | | V |
| V _{hys} | Input hysteresis (V _{IT+} - V _{IT-}) | | | 0.3 | | V |
| rį | Input resistance | $V_I = \pm 3 \text{ V to } \pm 25 \text{ V}$ | 3 | 5 | 7 | kΩ |

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

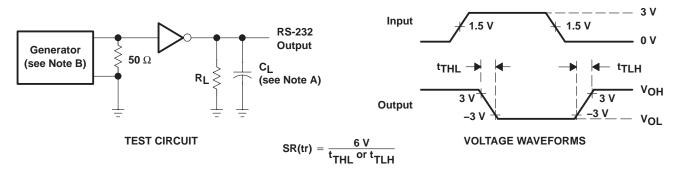
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 3)

| PARAMETER | | TEST CONDITIONS | MIN TYP [†] MAX | UNIT |
|-----------|---|-------------------------|--------------------------|------|
| tPLH | Propagation delay time, low- to high-level output | 0. 450 = 5 | 300 | ns |
| tPHL | Propagation delay time, high- to low-level output | C _L = 150 pF | 300 | ns |
| tsk(p) | Pulse skew [‡] | | 300 | ns |

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

‡ Pulse skew is defined as $|tp_{LH} - tp_{HL}|$ of each channel of the same device. NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

PARAMETER MEASUREMENT INFORMATION



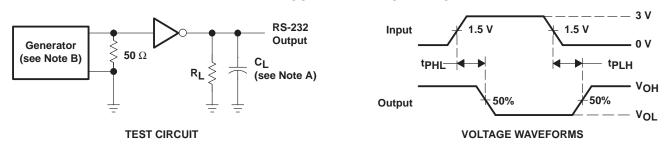
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50~\Omega$, 50% duty cycle, $t_\Gamma \le 10$ ns.

Figure 1. Driver Slew Rate



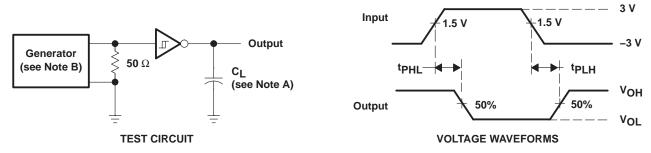
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew



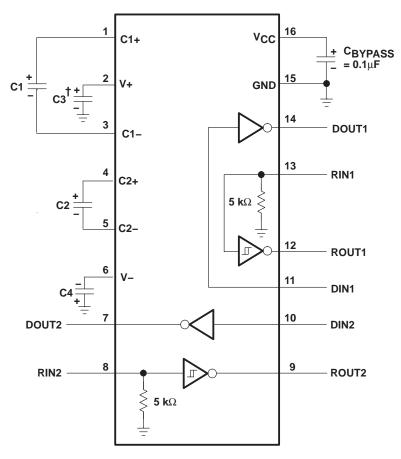
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times



APPLICATION INFORMATION



 $^{^{\}dagger}\,\text{C3}$ can be connected to $\text{V}_{\mbox{CC}}$ or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

| VCC | C1 | C2, C3, C4 |
|--|------------------------------|------------------------------|
| $\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$ | 0.1 μF 0.047 μF 0.1 μF | 0.1 μF 0.33 μF 0.47 μF |

Figure 4. Typical Operating Circuit and Capacitor Values